ASSP for Mobile Telephone

VCO (700 to 2000 MHz)

VC-30 Series

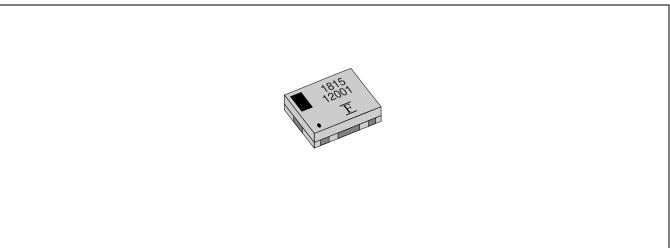
DESCRIPTION

With excellent C/N characteristics and low current consumption, this VCO series is ideal for CDMA, PCS and GSM mobile communication equipment. The VC-30 series can be used in any frequency band in the 700MHz to 2000MHz range. The device utilizes FUJITSU MEDIA DEVICE's high-frequency design technology, high-density mounting technology, and frequency adjustment technology to provide a high level of reliability in addition to high performance and small size.

FEATURES

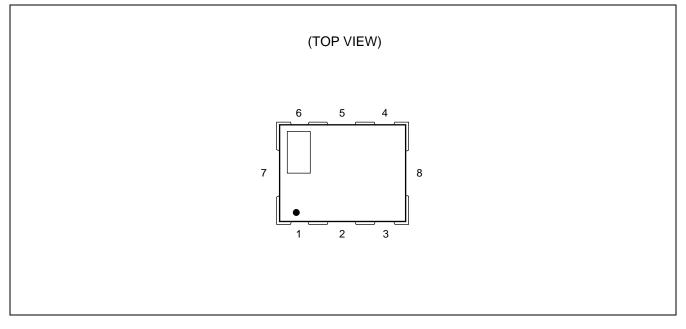
- Superior noise characteristics (C/N, S/N)
- · High level of stability in response to ambient temperature and load variations
- FUJITSU MEDIA DEVICE's proprietary fabrication process provides the uniformity of the central frequency distribution
- Small size, light-weight, slim-package : $7.9 \times 5.8 \times 2.0$ mm (Typ.)
- · SMD-type taping specifications suitable for automatic mounting and reflow soldering

PACKAGE



VC-30 Series

■ PIN ASSIGNMENT



■ PIN DESCRIPTION

Pin No.	Symbol	Description
1	Vt	Control voltage
2	GND	GND
3	Vcc	Power supply voltage
4	OUT	Output
5	GND	GND
6	GND	GND
7	GND	GND
8	GND	GND

■ PRODUCT LINEUP (STANDARD MODELS)

System	Center Frequency Band Width Power Supply (MHz) (MHz) Voltage (V)		Part Number	
CDMA	1591	±10	2.8 ± 0.2	VC-2R8A30-1591
CDMA	967	±13	3.35 ± 0.25	VC-3R3A30-0967
PCS	1750	±30	3.3 ± 0.15	VC-3R3A30-1750
K-PCS	1635	±15	3.3 ± 0.15	VC-3R3A30-1635
GSM	1815	±105	2.8 ± 0.1	VC-2R8A30-1815

ELECTRICAL CHARACTERISTICS

1. For CDMA (Part number : VC-2R8A30-1591)

Absolute Maximum Ratings

Parameter	Symbol	Rat	Unit	
Farameter	Symbol	Min.	Max.	Onic
Input DC voltage	Vcc	—	+ 3.0	V
Control voltage	Vt	—	+ 2.5	V
Operating temperature	Та	-20	+85	°C
Storage temperature	Tstg	-35	+90	°C
Storage humidity	Hstg	5	95	%

WARNING: VCO can be permanently damaged by application of stress (voltage, temperature, humidity, etc.) in excess of absolute maximum ratings. Do not exceed these ratings.

• Electrical Characteristics

(Ta = +25 °C±3 °C)

Parameter	Symbol	Conditions		Value		Unit
Farameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Current consumption	Icc	Vcc = 2.8 V, Vt = 1.35 V			6.2	mA
Frequency	fmin	$V_{CC} = 2.8 V, Vt = 0.5 V$		_	1581.0*	MHz
Frequency	fmax	Vcc = 2.8 V, Vt = 2.2 V	1601.0*	_		MHz
Control voltage sensitivity	kv	(fmax – fmin) / 1.7	25.0		37.0	MHz/V
Oscillator output	Po	Vcc = 2.8 V, Vt = 1.35 V	-5.0	_	1.0	dBm
C/N	0.01	Vcc = 2.8 V, Vt = 1.35 V, Offset = 1 kHz, BW = 1 Hz	65.0*			dBc/Hz
C/N	C/N	Vcc = 2.8 V, Vt = 1.35 V, Offset = 20 kHz, BW = 1 Hz	96.0*			dBc/Hz
Higher harmonics	Hs	Vcc = 2.8 V, Vt = 1.35 V, 2nd, 3rd			-10.0	dBc
Power supply variation	Push	$V_{CC} = 2.8 V \pm 0.2 V,$ Vt = 1.35 V		_	±1000	kHz
Load variation	Pull	Vcc = 2.8 V, Vt = 1.35 V, VSWR = 2 ALL PHASE			±1000	kHz
Temperature drift	Td	Ta = +25 (+60/–45) °C			±4000*	kHz

* : Ta = $-20 \circ C$ to $+85 \circ C$

2. For CDMA (Part number : VC-3R3A30-0967)

• Absolute Maximum Ratings

Parameter	Symbol	Ra	Rating		
Farameter	Symbol	Min.	Max.	Unit	
Input DC voltage	Vcc	—	+ 7.0	V	
Operating temperature	Та	-30	+80	°C	
Storage temperature	Tstg	-40	+90	°C	
Storage humidity	Hstg	5	95	%	

WARNING: VCO can be permanently damaged by application of stress (voltage, temperature, humidity, etc.) in excess of absolute maximum ratings. Do not exceed these ratings.

• Electrical Characteristics

			Value			
Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Current consumption	lcc	Vcc = 3.35 V, Vt = 1.7 V			6.0 6.4*	mA
Frequency	fmin	Vcc = 3.35 V, Vt = 0.7 V			954.0*	MHz
Frequency	fmax	Vcc = 3.35 V, Vt = 2.7 V	980.0*		_	MHz
Control voltage sensitivity	kv	(fmax – fmin) / 2.0	18.0*	23.0	28.0*	MHz/V
Oscillator output	Po	Vcc = 3.35 V, Vt = 1.7 V	-5.0 -6.0*	-2.5	0.0 1.0*	dBm
	C/N	Vcc = 3.35 V, Vt = 1.7 V, Offset = 1 kHz, BW = 1 Hz	70.0*			dBc/Hz
C/N		Vcc = 3.35 V, Vt = 1.7 V, Offset = 10 kHz, BW = 1 Hz	100.0*			dBc/Hz
C/N		Vcc = 3.35 V, Vt = 1.7 V, Offset = 30 kHz, BW = 1 Hz	110.0*			dBc/Hz
		Vcc = 3.35 V, Vt = 1.7 V, Offset = 60 kHz, BW = 1 Hz	115.0*			dBc/Hz
Higher harmonics	Hs	Vcc = 3.35 V, Vt = 1.7 V, 2nd, 3rd			-10.0*	dBc
Spurious	Sp	Vcc = 3.35 V, Vt = 1.7 V		_	-70.0*	dBc
Power supply variation	Push	$V_{CC} = 3.35 V \pm 0.25 V,$ Vt = 1.7 V			±800*	kHz
Load variation	Pull	Vcc = 3.35 V, Vt = 1.7 V, VSWR = 2 ALL PHASE			±1000*	kHz
Temperature drift	Td	Ta = +25 °C ± 55 °C	—		±3000*	kHz

(Ta = +25 °C ± 3 °C)

* : Ta = $-30 \degree$ C to $+80 \degree$ C

3. For PCS (Part number : VC-3R3A30-1750)

• Absolute Maximum Ratings

Parameter	Symbol	Rat	Unit	
Falameter	Symbol	Min.	Max.	Onit
Input DC voltage	Vcc	—	+ 5.0	V
Control voltage	Vt		+ 5.0	V
Operating temperature	Та	-30	+80	°C
Storage temperature	Tstg	-40	+125	°C
Storage humidity	Hstg	5	95	%

WARNING: VCO can be permanently damaged by application of stress (voltage, temperature, humidity, etc.) in excess of absolute maximum ratings. Do not exceed these ratings.

• Electrical Characteristics

 $(Ta = -30 \ ^{\circ}C \ to +80 \ ^{\circ}C)$

Demonstra	Querch et la constitue et			L Ins it		
Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Current consumption	lcc	Vcc = 3.3 V, Vt = 1.65 V			8.5	mA
Frequency	fmin	Vcc = 3.3 V, Vt = 0.3 V	—		1720.0	MHz
Frequency	fmax	Vcc = 3.3 V, Vt = 3.0 V	1780.0			MHz
Control voltage sensitivity	kv	(fmax – fmin) / 2.7	28.0	34.0	40.0	MHz/V
Oscillator output	Po	Vcc = 3.3 V, Vt = 1.65 V	-5.0	-2.0	1.0	dBm
		V _{CC} = 3.3 V, Vt = 1.65 V, Offset = 300 Hz, BW = 1 Hz	60.0			dBc/Hz
		Vcc = 3.3 V, Vt = 1.65 V, Offset = 1 kHz, BW = 1 Hz	70.0			dBc/Hz
	C/N	Vcc = 3.3 V, Vt = 1.65 V, Offset = 10 kHz, BW = 1 Hz	90.0			dBc/Hz
C/N		Vcc = 3.3 V, Vt = 1.65 V, Offset = 100 kHz, BW = 1 Hz	110.0		_	dBc/Hz
		Vcc = 3.3 V, Vt = 1.65 V, Offset = 625 kHz, BW = 1 Hz	129.0		_	dBc/Hz
		Vcc = 3.3 V, Vt = 1.65 V, Offset = 1.25 MHz, BW = 1 Hz	135.0			dBc/Hz
		$\label{eq:Vcc} \begin{array}{l} V_{cc}=3.3 \; V, \; Vt=1.65 \; V, \\ Offset \geq 2 \; MHz, \; BW=1 \; Hz \end{array}$	139.0			dBc/Hz
Higher harmonics	Hs	$V_{CC} = 3.3 V, Vt = 1.65 V,$ Up to 3rd			-10.0	dBc
Sourious	50	Vcc = 3.3 V, Vt = 1.65 V, Up to 6 GHz	_		-70	dBc
Spurious	Sp	Vcc = 3.3 V, Vt = 1.65 V, Carrier±100 MHz			-80	dBc
Power supply variation	Push	$V_{CC} = 3.3 V \pm 0.15 V,$ Vt = 1.65 V			±600	kHz
Load variation	Pull	Vcc = 3.3 V, Vt = 1.65 V, VSWR = 2 ALL PHASE	_		±1200	kHz
Temperature drift	Td	Ta = +25 °C ± 55 °C			±6000	kHz

4. For K-PCS (Part number : VC-3R3A30-1635)

Absolute Maximum Ratings

Parameter	Symbol	Ra	Unit	
Faiallieler	Symbol	Min.	Max.	Unit
Input DC voltage	Vcc	—	+ 6.0	V
Operating temperature	Та	-20	+70	°C
Storage temperature	Tstg	-30	+85	°C
Storage humidity	Hstg	5	95	%

WARNING: VCO can be permanently damaged by application of stress (voltage, temperature, humidity, etc.) in excess of absolute maximum ratings. Do not exceed these ratings.

• Electrical Characteristics

Parameter Sy	Symbol	Conditions	Min.	Value Typ.	Max.	Unit
Current consumption	lcc	Vcc = 3.3 V, Vt = 1.5 V			8.5	mA
Frequency	fmin	Vcc = 3.3 V, Vt = 0.5 V		_	1620.0	MHz
Frequency	fmax	$V_{CC} = 3.3 V, Vt = 2.5 V$	1650.0			MHz
Control voltage sensitivity	kv	(fmax – fmin) / 2	22.0	27.0	32.0	MHz/V
Oscillator output	Po	Vcc = 3.3 V, Vt = 1.5 V	-3.0	0.0	3.0	dBm
C/N	C/N	Vcc = 3.3 V, Vt = 1.5 V, Offset = 100 kHz, BW = 1 Hz	110.0			dBc/Hz
Higher harmonics	Hs	$V_{CC} = 3.3 V, Vt = 1.5 V,$ 2nd, 3rd			-10.0	dBc
Power supply variation	Push	$V_{CC} = 3.3 V \pm 0.15 V,$ Vt = 1.5 V		_	±1000	kHz
Load variation	Pull	Vcc = 3.3 V, Vt = 1.5 V, VSWR = 2 ALL PHASE			±1000	kHz
Temperature drift	Td	Ta = +25 °C ± 45 °C			±3000	kHz

(Ta = +25 °C ± 3 °C)

5. For GSM (Part number : VC-2R8A30-1815)

• Absolute Maximum Ratings

Parameter	Symbol	Ra	l Init	
	Symbol	Min.	Max.	Unit
Input DC voltage	Vcc	—	+ 3.0	V
Control voltage	Vt		+ 2.5	V
Operating temperature	Та	-25	+70	°C
Storage temperature	Tstg	-40	+85	°C
Storage humidity	Hstg	5	95	%

WARNING: VCO can be permanently damaged by application of stress (voltage, temperature, humidity, etc.) in excess of absolute maximum ratings. Do not exceed these ratings.

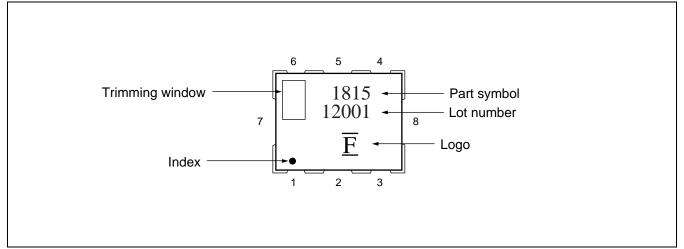
• Electrical Characteristics

(Ta = +25 °C ± 3 °C)

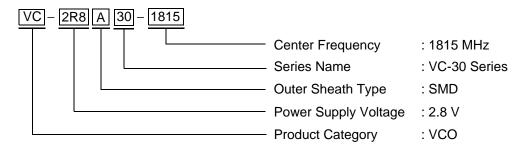
Parameter	Symbol Conditions			Unit		
Farameter	Зупрог	Conditions	Min.	Тур.	Max.	Unit
Current consumption	Icc	Vcc = 2.8 V, Vt = 1.35 V	_		20.0*	mA
Frequency	fmin	Vcc = 2.8 V, Vt = 0.3 V			1710.0*	MHz
Frequency	fmax	Vcc = 2.8 V, Vt = 2.4 V	1920.0*		_	MHz
Control voltage sensitivity	kv	(fmax – fmin) / 2.1	110.0*		140.0*	MHz/V
Oscillator output	Po	Vcc = 2.8 V, Vt = 1.35 V	3.0 2.0*		7.0 8.0*	dBm
C/N	C/N	Vcc = 2.8 V, Vt = 1.35 V, Offset = 10 kHz, BW = 1 Hz	90.0*			dBc/Hz
C/N		Vcc = 2.8 V, Vt = 1.35 V, Offset = 400 kHz, BW = 1 Hz	118.0*	_		dBc/Hz
Higher harmonics	Hs	$V_{CC} = 2.8 V, Vt = 1.35 V,$ Up to 3rd			-15.0*	dBc
Power supply variation	Push	$V_{CC} = 2.8 V \pm 0.1 V,$ Vt = 1.35 V	_	_	±2000*	kHz
Load variation	Pull	Vcc = 2.8 V, Vt = 1.35 V, VSWR = 2 ALL PHASE	—		±2000*	kHz
Temperature drift	Td	Ta = +25 (+45/–50) °C			±8000*	kHz

* : Ta = -25 °C to +70 °C

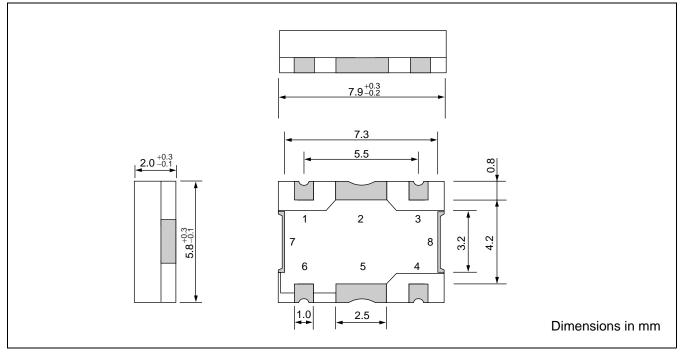
■ MARKING



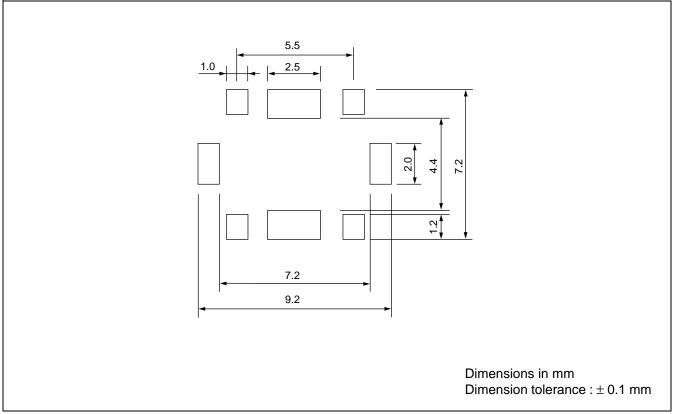
PART NUMBER DESIGNATION



■ PACKAGE DIMENSION



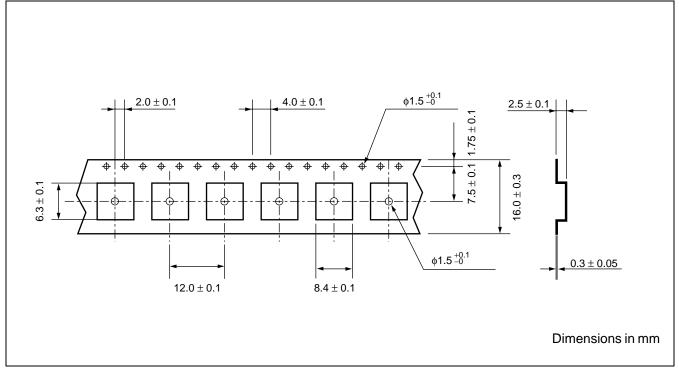
■ RECOMMENDED PATTERN FOR SOLDERING



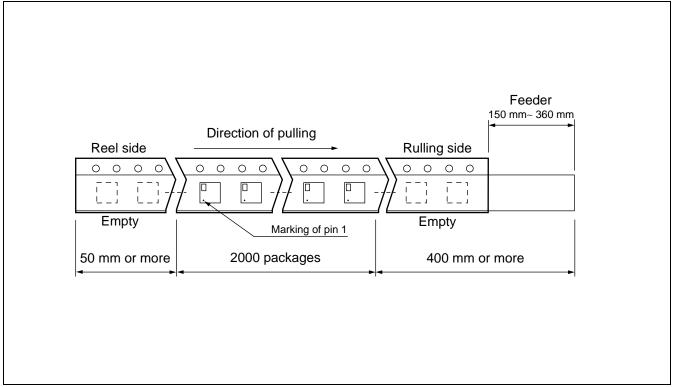
■ TAPING AND PACKAGING

Volume : 2000 pcs/reel

(1) Carrier Tape and Packaging

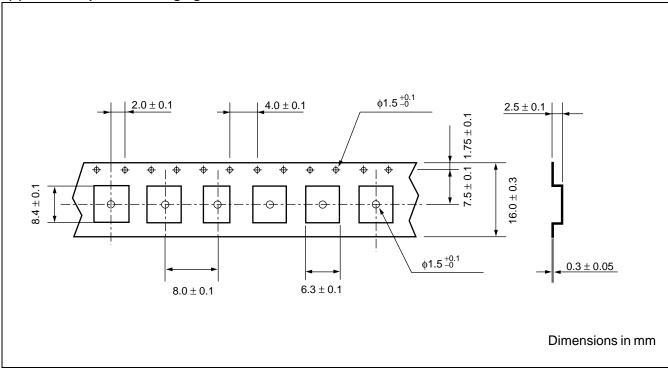


(2) Taping Layout

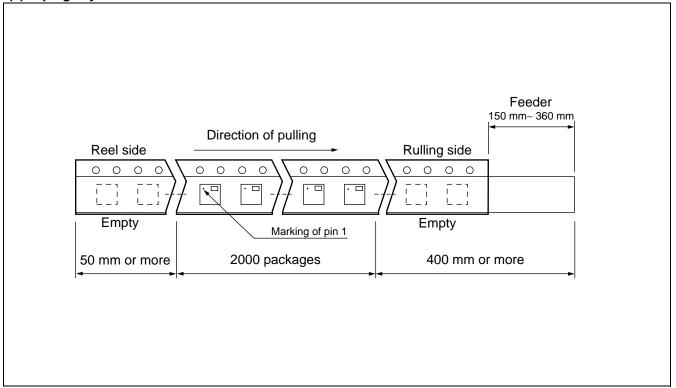


• Volume : 3000 pcs/reel

(1) Carrier Tape and Packaging

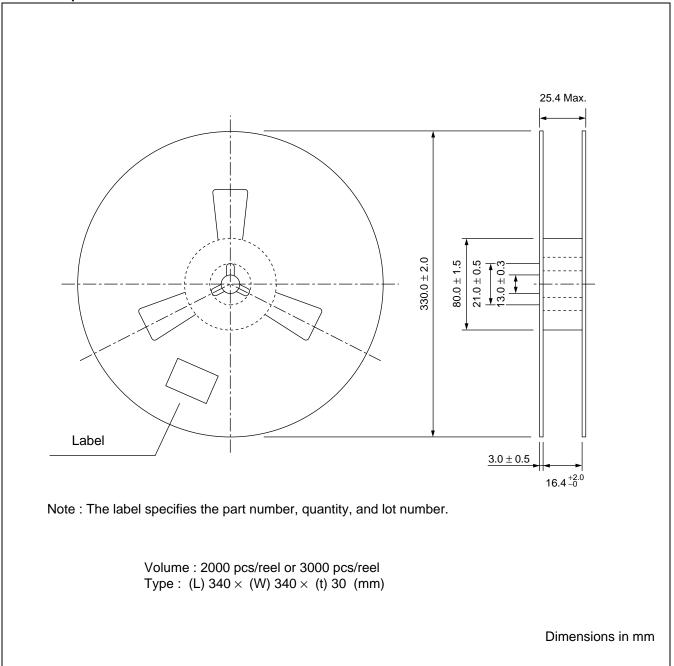


(2) Taping Layout



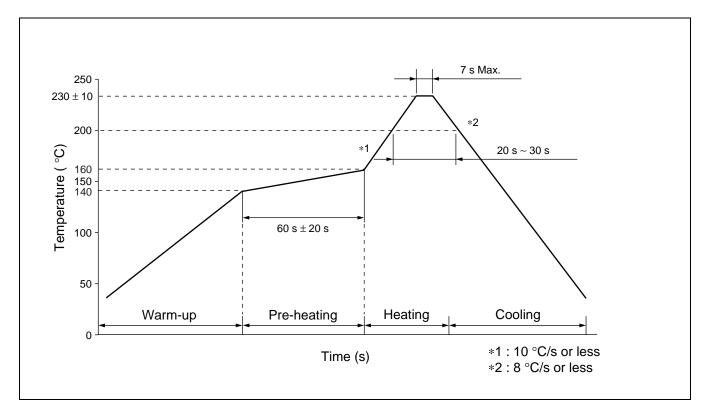
VC-30 Series

• Reel Shape and Dimensions



■ REFLOW MOUNTING CONDITIONS (RECOMMENDED)

- Perform mounting using the temperature profile shown below. To prevent thermal stress to the VCO, ensure gentle temperature gradients and use preheating whenever possible. (Recommended preheating: 140 °C to 160 °C for 60 s ± 20 s)
- Always consult FUJITSU MEDIA DEVICE beforehand if mounting more than once.
- Never remove a VCO that has already been mounted and attempt to reuse.
- For mounting, use a general-purpose flux suitable for mounting electronic components.



WASHING CONDITIONS

- Washing solution: Use isopropyl alcohol.
- Washing procedure: Immersion or steam cleaning is recommended.
- Washing time: For immersion: Less than 5 minutes at 40 °C or less.
 - For steam: Less than 2 minutes at 90 °C or less is recommended.

VC-30 Series

FUJITSU MEDIA DEVICES LIMITED

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